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Study of electromagnetic enhancement for surface enhanced Raman spectroscopy of SiC graphene

Jing Niu,¹ Viet Giang Truong,¹ Han Huang,^{2,3} Sudhiranjan Tripathy,⁴ Caiyu Qiu,⁵
Andrew T. S. Wee,^{2,3} Ting Yu,^{2,3,5} and Hyunsoo Yang^{1,3,a)}

¹Department of Electrical and Computer Engineering, National University of Singapore, 117576 Singapore

²Department of Physics, National University of Singapore, 117542 Singapore

³Graphene Research Centre, National University of Singapore, 117546 Singapore

⁴Institute of Materials Research and Engineering, 117602 Singapore

⁵Division of Physics and Applied Physics, School of Physical and Mathematical Sciences, Nanyang Technological University, 637371 Singapore

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The electromagnetic enhancement for surface enhanced Raman spectroscopy (SERS) of graphene is studied by inserting a layer of Al_2O_3 between epitaxial graphene and Au nanoparticles. Different excitation lasers are utilized to study the relationship between laser wavelength and SERS. The theoretical calculation shows that the extinction spectrum of Au nanoparticles is modulated by the presence of graphene. The experimental results of the relationship between the excitation laser wavelength and the enhancement factor fit well with the calculated results. An exponential relationship is observed between the enhancement factor and the thickness of the spacer layer. © 2012 American Institute of Physics. [<http://dx.doi.org/10.1063/1.4712054>]

Since graphene was made by mechanical exfoliation in 2004, it has stirred enormous interest from various research fields due to its extraordinary properties including a high electron mobility of up to $200\,000\text{ cm}^2/\text{Vs}$, large thermal conductivity exceeding 3000 W/mK at room temperature, and low opacity of $\sim 2.3\%$.^{1–8} The properties of graphene can be altered largely by its fine structure, for example, through the number of layers, doping level, and defects.^{9–11} Raman spectroscopy is a common and non-destructive tool to characterize the structural characteristics of graphene. The number of layers of graphene can be easily distinguished by the evolution of the shape of the 2D peak and the shifting of the peak position of both the 2D and G peaks.¹² It is also capable of monitoring the doping, defects, thermal conductivity, and strain of graphene.^{13–16} However, the Raman signal of graphene is not strong enough for some fine structural characteristics such as vacancies, edge structures, and crumpling.¹⁷ This is mainly due to the fact that, for Raman scattering, the majority of the incident light undergoes Rayleigh scattering which does not contribute to the Raman signal, and the greater part of the incident light is transmitted through graphene without contributing to the scattered radiation.¹⁷ Therefore, researchers are continuously working on new methods to improve the Raman signal strength.

The substrate commonly used for mechanical exfoliated graphene is a Si substrate capped with a layer of SiO_2 with a specific thickness, which is designed for easier observation of exfoliated graphene under optical microscopy. It is found that this special substrate structure not only enhances the optical contrast between graphene and the background, but also provides an enhancement of the Raman signal through interference-enhanced Raman scattering (IERS).¹⁸ Hence, an exfoliated graphene with the special Si/ SiO_2 substrate always has a stronger Raman signal compared with epitaxial

graphene on SiC substrates. The epitaxial graphene on SiC substrates is a promising candidate for electronic applications, since it provides a semiconducting substrate by default and comprises a uniform layer compared to chemical vapor deposition (CVD) graphene.² In addition to IERS, surface enhanced Raman spectroscopy (SERS) is another method that boosts the strength of the Raman signal.^{19,20} Thus far, most of the research studies about SERS of graphene have been carried out on exfoliated graphene, whereas no results have been published for epitaxial graphene on SiC substrates. For SERS, metal nanoparticles are often included in the system to induce the primary mechanisms of the enhancement which is the localized electromagnetic field surrounding the nanoparticles caused by localized surface plasmon resonances (LSPR).²¹ Two main mechanisms of SERS are chemical enhancement, which requires a direct contact between graphene and nanoparticles, and electromagnetic enhancement.^{22–24}

In this letter, a layer of Al_2O_3 with various thicknesses is inserted between graphene and Au nanoparticles to study the electromagnetic enhancement of SERS solely by eliminating the possibility of chemical enhancement of SERS caused by charge transfer. In addition, through a variation of the thickness of Al_2O_3 , the thickness effect of the spacer layer on SERS can be studied. The experimental result of the enhancement factor as a function of the excitation laser wavelength agrees well with the theoretical calculation of the extinction spectrum of LSPR, providing a selection guide to laser wavelengths in order to obtain the maximum SERS of graphene. Furthermore, an exponential relationship between the thicknesses of the Al_2O_3 insulating layer and the electromagnetic enhancement factor is observed.

The graphene samples used in our experiment are single layer graphene thin films grown on a Si-terminated 6H-SiC (0001) surface. The film thickness is confirmed by scanning tunneling microscopy (STM) followed by Raman

^{a)}E-mail address: eleyang@nus.edu.sg.

FIG. 1. (a) Schematic illustration of sample fabrication process. (b) The transmission spectra of the area without and with Au nanoparticles on the same sample (inset: SEM image of Au nanoparticles formed on top of Al₂O₃).

spectroscopy.^{25,26} A layer of Al with a thickness of ~ 3 nm was deposited on top of the sample by an electron beam evaporator followed by naturally occurring oxidation in an ambient environment. The thickness of the thin layer is monitored by a quartz crystal during the evaporation process and is confirmed by an ellipsometer. For a thicker Al₂O₃ film, the above steps are repeated. Metal nanoparticles are formed by evaporating a thin Au film of 5 nm, followed by annealing in 500 °C under a N₂ environment for 20 min. The fabrication processes are shown in Fig. 1(a). The scanning electron microscope (SEM) images of metal nanoparticles formed on top of the sample with different Al₂O₃ thicknesses show no noticeable change in the average size of diameter (~ 15 nm). The inset of Fig. 1(b) shows one of the SEM images of nanoparticles formed on top of the sample after annealing.

The transmission spectrum shown in Fig. 1(b) is obtained to verify the excitation of localized surface plasmons in the structure. The transmission spectra without and with Au nanoparticles show apparent differences. The transmission spectrum with Au nanoparticles shows an additional valley compared with that without nanoparticles. The minimum transmission appears at ~ 560 nm which matches well with the LSPR wavelength of gold nanoparticles.²⁷

Raman spectra of the same sample are taken with four excitation lasers with different wavelengths (325, 488, 532, and 785 nm) on the area without and with nanoparticles, as shown in Figs. 2(a) and 2(b), respectively. The thickness of Al₂O₃ is 3 nm. The enhancement factor is calculated through two steps. First, the intensity of the G peak (~ 1580 cm⁻¹) for each spectrum is normalized with the SiC substrate peak at ~ 1519 cm⁻¹. The SiC substrate peak is comparable for samples deposited without and with nanoparticles under the same experimental conditions on the same sample, thus this step allows us to get a more reliable comparison result. Then for each wavelength, the enhancement factor is computed by using the intensity of the G peak obtained with Au particles divided by that without particles. It is observed that the enhancement factor of G peak is always greater than 1, when the sample is capped with Au particles. Figure 2(c) shows the enhancement factors of four different excitation lasers, indicating the maximum enhancement with a 532 nm laser. Previously, detailed wavelength-scanned surface-enhanced Raman excitation spectroscopy (WS-SERES) and plasmon-sampled surface-enhanced Raman excitation spectroscopy demonstrated that the maximum SERS enhancement occurs

when the excitation wavelength of the laser is slightly blue-shifted from the resonance wavelength of LSPR.^{28–30} Considering the above observation and that 532 nm is the nearest laser wavelength to the surface plasmon resonance wavelength (560 nm) of Au particles, strong electromagnetic fields surrounding the Au particles induce more electromagnetic enhancement to the Raman intensity. However, an unexpectedly low enhancement factor is obtained, when the 488 nm laser is utilized. As 488 nm is rather close to the LSPR wavelength, its enhancement should be higher than the one obtained with either the 325 or 785 nm laser.

FIG. 2. Raman spectra obtained on the same sample with different excitation laser wavelengths (325, 488, 532, and 785 nm) without (a) and with (b) nanoparticles. The thickness of Al₂O₃ is 3 nm. (c) Enhancement factor of the G peak and the calculated extinction efficiency of Au nanoparticles vs. wavelength of excitation lasers (inset: schematic illustration of the structure used for theoretical calculation).

It is known through WS-SERES that the line shape of SERS should be similar to that of the LSPR extinction spectra.^{28,31} In order to understand the above observation, theoretical calculations of the extinction efficiency based on dipole approximation have been carried out. In the calculation, the substrate is assumed to be flat with semi-infinite thickness, and an Au nanoparticle with a diameter of 15 nm is embedded in a mixture of Al₂O₃ (30%) and air (70%) above graphene. The dielectric constant of graphene is calculated as $\epsilon_3 = 1 + i\sigma_g/\omega\epsilon_0 d_g$, where ϵ_0 , ϵ_3 , σ_g , and d_g are the permittivity of vacuum, the dielectric constant, optical sheet conductivity, and thickness of graphene (0.34 nm), respectively. The calculation of the dielectric constant of graphene is based on an assumption that the optical response of the graphene layer is given by optical sheet conductivity.³² The bulk dielectric constant of gold and Al₂O₃ is obtained from the literature.³³ The polarizability of a metal nanoparticle above a conductive substrate can be written as

$$\alpha = 4\pi a^3 \left(\frac{\epsilon_1 - \epsilon_2}{\epsilon_1 + 2\epsilon_2} \right) \left[1 - \beta \left(\frac{a}{2d} \right)^3 \left(\frac{\epsilon_1 - \epsilon_2}{\epsilon_1 + 2\epsilon_2} \right) \left(\frac{\epsilon_3 - \epsilon_2}{\epsilon_3 + \epsilon_2} \right) \right]^{-1}, \quad (1)$$

where α is the polarizability, a is the radius of the sphere (7.5 nm), β is taken as 1 for lateral electric fields, and d is the distance from the center of the gold sphere to the substrate surface.³⁴ ϵ_1 , ϵ_2 , and ϵ_3 are the dielectric constants of gold, surrounding media, and the substrate, respectively. The absorption efficiency Q_{abs} is given by $Q_{abs} = [k/\pi a^2] \text{Im}(\alpha)$, and the scattering efficiency Q_{sca} is given by $Q_{sca} = [k^4/6\pi^2 a^2] |\alpha|^2$.³⁴ The summation of these two gives the extinction efficiency Q_{ext} which is plotted in Fig. 2(c). It is clear that the calculation result fits qualitatively well with the experimental data. This shows that the presence of graphene can change the extinction spectrum of Au nanoparticles substantially, which leads to a nonmonotonic change in the enhancement factor of SERS with different excitation wavelength lasers. The enhancement factor can be improved by optimizing the size and interspaces of the nanoparticles.

The relationship between the enhancement factor and the thickness of the Al₂O₃ spacer layer has been also investigated. For different Al₂O₃ thicknesses, the Raman data before and after the formation of Au nanoparticles have been measured. The excitation wavelength of the laser is 488 nm. Without Au nanoparticles in the structure, the intensity of the G peak does not change with various Al₂O₃ thicknesses as shown in Fig. 3(a). After forming Au nanoparticles, the enhancement factor of the G peak decreases with an increase in the Al₂O₃ thickness, as indicated in Fig. 3(b). The enhancement factor falls off exponentially with an increase in the insulator thickness, as shown in Fig. 3(c). An enhancement factor of 1.2 is still present when the thickness of Al₂O₃ increases to 12 nm. The extinction efficiency is calculated with various Al₂O₃ thicknesses based on Eq. (1) as shown in Fig. 3(c), and it shows a decreasing trend similar to the experimental data. The observed data can be better accounted for by the exponential decay of electromagnetic fields of localized surface plasmon away from its excitation source (Au nanoparticles) because of the evanescent nature of the LSPR.³⁵ One recent report also showed an exponential

FIG. 3. Raman spectra of SiC graphene capped with different thicknesses of Al₂O₃ from samples without (a) and with (b) nanoparticles. (c) The relationship between the enhancement factor and the thickness of the Al₂O₃ spacer layer. The calculated extinction efficiency is shown as well. The excitation wavelength of the laser is 488 nm. The y-axis in (c) is on a logarithmic scale (inset: Raman spectra of SiC graphene samples with different thicknesses of Al₂O₃ after removing Au nanoparticles with aqua regia).

decrease of the photoluminescence enhancement ratio as the thickness of the SiO₂ spacer between graphene and the ZnO layer increases.³⁶

In order to ensure that there is no diffusion of Au nanoparticles through the Al₂O₃ spacer layer and get in contact with the graphene layer which will allow charge transfer between Au nanoparticles and graphene, Au nanoparticles are etched away using aqua regia and Raman spectra of the samples are taken again as shown in the inset of Fig. 3(c). As shown in the spectra, the enhancement of G peak is absent after Au nanoparticles are etched away. This confirms that the presence of the spacer layer eliminates the possibility of any chemical enhancement of SERS caused by charge transfer. In addition, the change in the thickness of an insulator layer also affects the scattering of light and the modulation of the surface plasmon resonance wavelength³⁷ due to graphene could change the enhancement factor of the Raman intensity. This result can be applied to the research field where graphene is utilized as a substrate to obtain more strong Raman signals in the characterization of low concentration molecules. Experimental results show that graphene can be considered as a substrate for various molecules to obtain better Raman spectroscopy.^{38,39} Recently, Au thin films on graphene have been also used to facilitate enhanced Raman signals of molecules.⁴⁰ Our proposed structure with an insulating layer will be particularly useful for certain experiments in which a direct contact between a conducting layer and molecules is not preferred.

In conclusion, we have studied the SERS induced by metal nanoparticles on SiC epitaxial graphene. By inserting a layer of Al₂O₃ insulator between graphene and nanoparticles, the chemical enhancement of Raman spectroscopy caused by charge transfer is ruled out. The enhancement of Raman scattering is due to the near-field plasmonic effects induced by Au nanoparticles. Excitation lasers with different wavelengths have been utilized to study the relationship between the laser wavelength and the SERS. Theoretical calculations show that the extinction spectrum of Au nanoparticles is modulated by graphene. The experimental results of the relationship between the excitation laser wavelength and the enhancement factor match well with the calculated results. An exponential relationship is observed between the enhancement factor and the thickness of the Al₂O₃ spacer layer.

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